

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT MULTI CHIP

TD62M8604AF

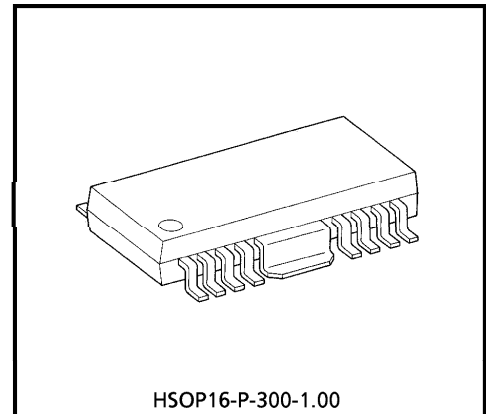
8ch LOW SATURATION VOLTAGE SOURCE DRIVER

The TD62M8604AF is Multi Chip IC incorporates 8 low saturation discrete (PNP : 2SA1680) transistors.

This IC is suitable for a battery use motor drive and LED display module applications.

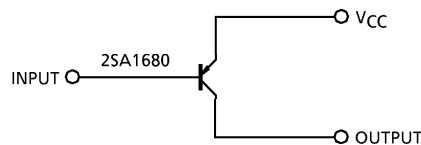
FEATURES

- Suitable for Motor drive circuit and LED display module
- Low Saturation Voltage
 $V_{CE(sat)} = -0.5V$ (Typ.) at $I_C = -0.5A$
 $V_{BE(sat)} = -1.2V$ (Max.) at $I_C = -1.0A$
- HSOP16 power small package sealed

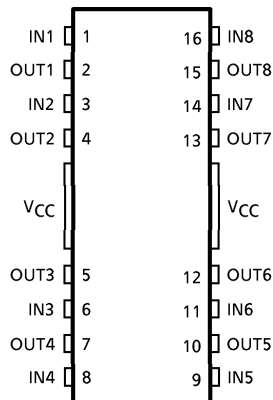


Weight : 0.50g (Typ.)

BLOCK DIAGRAM



PIN CONNECTION (TOP VIEW)



961001EBA2

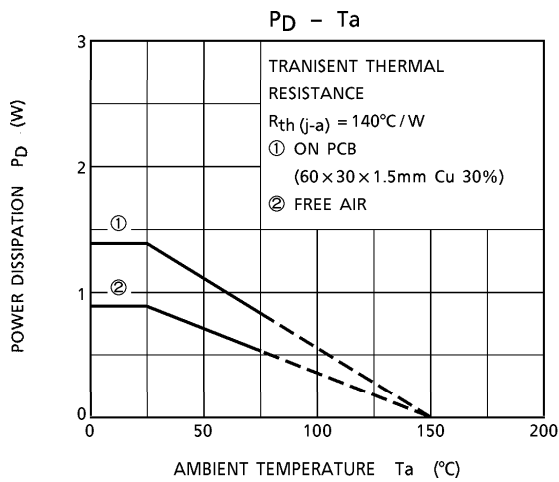
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MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|-----------------------|------------------|----------|--------|
| Supply Voltage | V _{CC} | - 50 | V |
| Breakdown Voltage | V _{CBO} | - 60 | V |
| Breakdown Voltage | V _{CEO} | - 50 | V |
| Breakdown Voltage | V _{EBO} | - 6 | V |
| Output Current | I _O | - 2 | A / ch |
| Base Current | I _B | - 0.2 | A |
| Power Dissipation | P _D | 900 | mW |
| Junction Temperature | T _j | 150 | °C |
| Operating Temperature | T _{opr} | - 40~85 | °C |
| Storage Temperature | T _{stg} | - 55~150 | °C |

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CIR-CUIT | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|----------------------|-----------------------|---------------|---|------|------|------|------|
| Current Gain | h _{FE} (1) | — | V _{CE} = -2V, I _C = -0.1A | 120 | — | 400 | |
| | h _{FE} (2) | — | V _{CE} = -2V, I _C = -1.5A | 40 | — | — | |
| Saturation Voltage | V _{CE} (sat) | — | I _C = -1A, I _B = -50mA | — | — | -0.5 | V |
| | V _{BE} (sat) | — | I _C = -1A, I _B = -50mA | — | — | -1.2 | |
| Transition Frequency | f _T | — | V _{CE} = -2V, I _C = -0.1A | — | 100 | — | MHz |
| Leakage Current | I _{OL} | — | V _{CC} = -50V | — | 0 | -5 | μA |

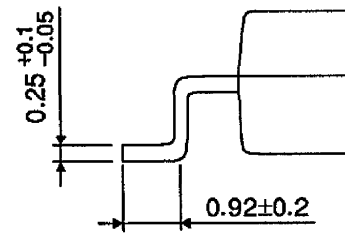
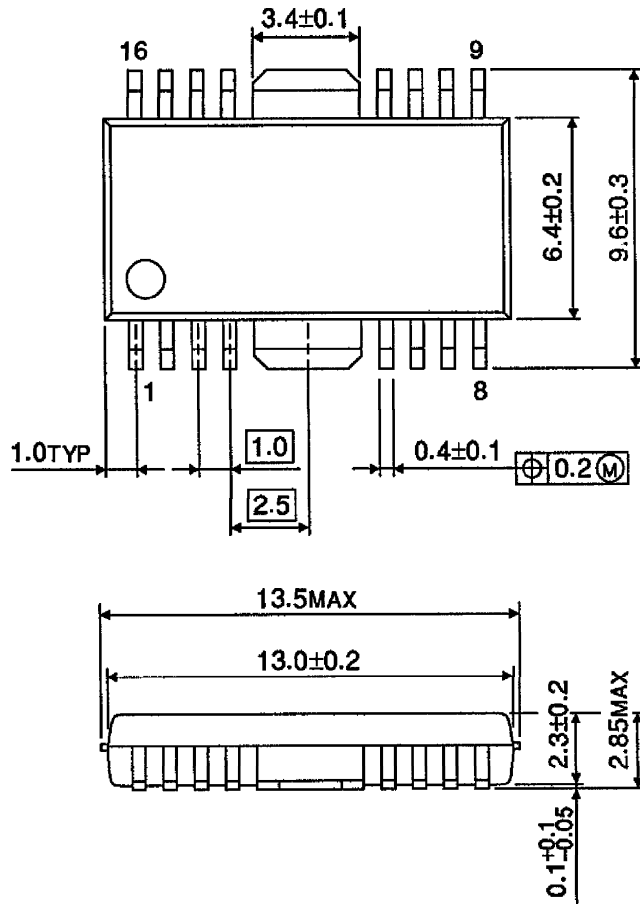


PRECAUTIONS for USING

Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

OUTLINE DRAWING
HSOP16-P-300-1.00

Unit : mm



Weight : 0.50g (Typ.)